Taiwan Semiconductor

1A, 50V - 1000V Glass Passivated Rectifier

FEATURES

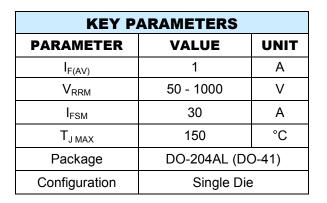
- Glass passivated chip junction
- High current capability, Low VF
- High reliability
- High surge current capability
- Low power loss, high efficiency
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- TV
- Monitor

MECHANICAL DATA

- Case: DO-204AL (DO-41)
- Molding compound meets UL 94V-0 flammability rating
- Packing code with suffix "G" means green compound (halogen-free)
- Terminal: Pure tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: As marked
- Weight: 0.33 g (approximately)







ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)									
PARAMETER	SYMBOL	1N4001	1N4002	1N4003	1N4004	1N4005	1N4006	1N4007	UNIT
		G-K	G-K	G-K	G-K	G-K	G-K	G-K	•
Marking code on the device		1N4001G	1N4002G	1N4003G	1N4004G	1N4005G	1N4006G	1N4007G	
Repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Forward current	I _{F(AV)}				1				А
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}				30				A
Junction temperature	Т _Ј			-	55 to +15	0			°C
Storage temperature	T _{STG}		- 55 to +150		°C				



THERMAL PERFORMANCE			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	80	°C/W

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage per diode ⁽¹⁾	I _F = 1A,T _J = 25°C	V _F	-	1	V
Reverse current @ rated V_R per diode $^{(2)}$	T _J = 25°C	- I _R	-	5	μA
	T _J = 125°C		-	100	μA
Junction capacitance	1 MHz, V _R =4.0V	CJ	10	-	pF

Notes:

1. Pulse test with PW=0.3 ms

2. Pulse test with PW=30 ms

ORDERING INFORMATION				
PART NO.	PACKIN G CODE	PACKING CODE SUFFIX	PACKAGE	PACKING
	A0		DO-41	3,000 / Ammo box (52mm taping)
1N400xG-K	R0		DO-41	5,000 / 13" Paper reel
(Note 1, 2)	R1	G	DO-41	5,000 / 13" Paper reel (Reverse)
	В0		DO-41	1,000 / Bulk packing

Notes:

1. "x" defines voltage from 50V (1N4001G-K) to 1000V (1N4007G-K)

2. Whole series with green compound (halogen-free)

EXAMPLE P/N					
EXAMPLE P/N	PART NO.	PACKING Code	PACKING CODE SUFFIX	DESCRIPTION	
1N4001G-K A0G	1N4001G-K	A0	G	Green compound	



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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

(P) 1.5 1 1 1 1 0.5 0.5 0 25 50 75 100 125 150 AMBIENT TEMPERATURE(°C)

Fig1. Forward Current Derating Curve

Fig2. Typical Junction Capacitance

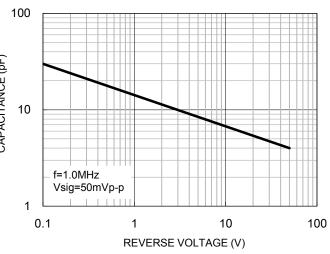
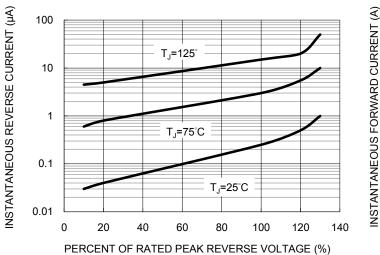


Fig3. Typical Reverse Characteristics

Fig4. Typical Forward Characteristics



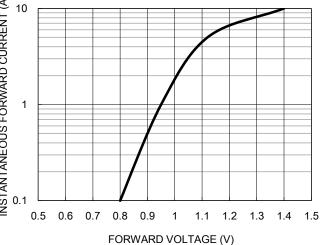
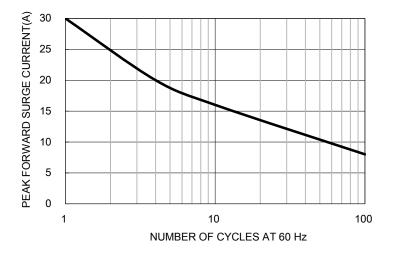




Fig5. Maximum Non-repetitive Forward Surge Current

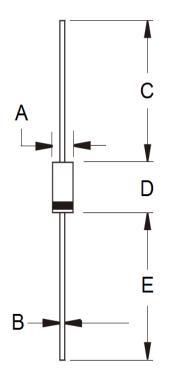






PACKAGE OUTLINE DIMENSIONS

DO-204AL (DO-41)



DIM.	Unit (ı	nm)	Unit (inch)		
Dilvi.	Min	Мах	Min	Max	
A	2.00	2.70	0.079	0.106	
В	0.71	0.86	0.028	0.034	
С	25.40	-	1.000	-	
D	4.20	5.20	0.165	0.205	
Е	25.40	-	1.000	-	

MARKING DIAGRAM



P/N	= Marking Code

- G = Green Compound YWW = Date Code
- = Factory Code F



<u>1N4001G-K - 1N4007G-K</u>

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